# 25C D 8235LO5 0004807 3 SIEG 7-35-/7 NPN Silicon Planar Transistors BSX 45 BSX 45 BSX 47

BSX 45, BSX 46, and BSX 47 are epitaxial NPN silicon planar transistors in TO 39 case (5 C 3 DIN 41873). Their collectors are electrically connected to their cases. The transistors are particularly suitable for AF amplifiers and AF switching applications up to 1 A.

| Туре                 | Ordering code  |                             |
|----------------------|----------------|-----------------------------|
| BSX 45 <sup>1)</sup> | Q60218-X45     |                             |
| BSX 45-6             | Q60218-X45-V6  | ¢0,5                        |
| BSX 45-10            | Q60218-X45-V10 |                             |
| BSX 45-16            | Q60218-X45-V16 |                             |
| BSX 461)             | Q60218-X46     | ا ا                         |
| BSX 46-6             | Q60218-X46-V6  | 13,5±1  6,6 <sub>-0,4</sub> |
| BSX 46-10            | Q60218-X46-V10 | Approx. weight 1.5 g        |
| BSX 46-16            | Q60218-X46-V16 | , aprox. no.g no g          |
| BSX 471)             | Q60218-X47     |                             |
| BSX 47-6             | Q60218-X47-V6  |                             |
| BSX 47-10            | Q60218-X47-V10 |                             |



Dimensions in mm

| Maximum ratings                                     |                  | BSX 45      | BSX 46      | BSX 47     |     |
|---|------------------|-------------|-------------|------------|-----|
| Collector-emitter voltage                           | V <sub>CEO</sub> | 40          | 60          | 80         | V   |
| Collector-emitter voltage                           | VCES             | 80          | 100         | 120        | l v |
| Emitter-base voltage                                | VEBO             | 7           | 7           | 7          | lv  |
| Collector current                                   | $I_{C}$          | 1           | 1           | 1          | A   |
| Base current  | $I_{B}$          | 0.2         | 0.2         | 0.2        | A   |
| Junction temperature                                | T <sub>i</sub>   | 200         | 200         | 200        | °C  |
| Storage temperature range                           | T <sub>stg</sub> | Ì           | ~65 to +200 |            | \°C |
| Total power dissipation (T <sub>case</sub> ≤ 25 °C) | Ptot             | 5           | 5           | 5          | W   |
| Thermal resistance                                  |                  | •           |             |            |     |
| Junction to ambient air                             | $R_{\rm thJA}$   | ≤ 200       | ≤ 200       | ≦ 200      | K/W |
| Junction to case                                    | RthJC            | <b>≤ 35</b> | ≤ 35        | <b>≦35</b> | K/W |

### Static characteristics ( $T_{amb} = 25$ °C)

Transistors BSX 45, BSX 46, and BSX 47 are grouped according to their DC current gain  $h_{\rm FE}$  at  $I_{\rm C}$  = 100 mA and  $V_{\rm CE}$  = 1 V. The different groups are marked by figures of the DIN-R 5 standard series.

| Туре                      | BSX 45<br>BSX 46<br>BSX 47                        | BSX 45<br>BSX 46<br>BSX 47                        | BSX 45<br>BSX 46                                  | BSX 45<br>BSX 46<br>BSX 47         |  |
|---------------------------|---|---|---|------------------------------------|--|
| h <sub>FE</sub> group     | 6   | 10  | 16  |                                    |  |
| I <sub>C</sub> mA         | h <sub>FE</sub><br>I <sub>C</sub> /I <sub>B</sub> | h <sub>FE</sub><br>I <sub>C</sub> /I <sub>B</sub> | h <sub>FE</sub><br>I <sub>C</sub> /I <sub>B</sub> | V <sub>BE</sub>                    |  |
| 0.1<br>100<br>500<br>1000 | 28 (> 10)<br>63 (40 to 100)<br>25 (> 15)<br>15    | 40 (> 15)<br>100 (63 to 160)<br>40 (> 25)<br>20   | 90 (> 25)<br>160 (100 to 250)<br>60 (> 35)<br>30  | -<br><1<br>0.75 to 1.5<br>1.3 (<2) |  |

In case of orders without an exact indication of the current amplification wanted, a transistor will be delivered
of that current amplification group available at stock.

853

25C 04808

**BSX 45** BSX 46 BSX 47

### SIEMENS AKTIENGESELLSCHAF

| Static characteristics ( $T_{amb} = 25$   | 5°C)                 | BSX 45   | BSX 46   | BSX 47     |    |
|---|----------------------|----------|----------|------------|----|
| Collector-emitter saturation voltage $(I_C = 1 \text{ A}; h_{FE} = 10)$ Collector-emitter saturation voltage                                | V <sub>CEsat</sub>   | 0.7 (<1) | 0.7 (<1) | _          | V  |
| Collector-emitter saturation voltage $(I_C = 0.5 \text{ A}; h_{FE} = 20)$<br>Collector cutoff current                                       | V <sub>CEsat</sub>   | -        | -        | 0.5 (<0.9) | ٧  |
| (V <sub>CES</sub> = 60 V) Collector cutoff current  | $I_{CES}$            | 1 (<30)  | 1 (<30)  | _          | nA |
| (V <sub>CES</sub> = 60 V; T <sub>amb</sub> = 150°C)<br>Collector cutoff current   | I <sub>CES</sub>     | 1 (<10)  | 1 (<10)  | -          | μΑ |
| (V <sub>CES</sub> = 80 V)<br>Collector cutoff current   | $I_{CES}$            | _        | _        | <30        | nA |
| $(V_{CES} = 80 \text{ V}; T_{amb} = 150 ^{\circ}\text{C})$<br>Collector cutoff current<br>$(V_{CE} = 60 \text{ V}; V_{BE} = 0.2 \text{ V};$ | I <sub>CES</sub>     | _        | -        | <10        | μА |
| $T_{amb} = 100$ °C)<br>Collector cutoff current<br>( $V_{CE} = 80$ V; $V_{BE} = 0.2$ V;   | $I_{CEX}$            | <50      | <50      | -          | μΑ |
| T <sub>amb</sub> = 100°C)<br>Emitter cutoff current   | $I_{CEX}$            | -        | -        | <50        | μΑ |
| $(V_{EBO} = 5 \text{ V})$<br>Collector-emitter breakdown<br>voltage ( $I_{CE} = 50 \text{ mA}$ ;<br>pulse length = 200 μs;                  | I <sub>EBO</sub>     | <10      | <10      | <10        | nΑ |
| duty cycle 1%) Collector-emitter breakdown  | V <sub>(BR)CEO</sub> | >40      | >60      | >80        | ٧  |
| voltage (I <sub>CES</sub> = 100 μA)<br>Emitter-base breakdown   | V <sub>(BR)CES</sub> | >80      | >100     | >120       | ٧  |
| voltage ( $I_{EBO} = 100 \mu\text{A}$ )   | V <sub>(BR)E80</sub> | >7       | >7       | >7         | V  |

### Dynamic characteristics ( $T_{amb} = 25$ °C)

| Transition frequency $(I_C = 50 \text{ mA}; V_{CF} = 10 \text{ V};$ |                  |      |      | •    |     |
|---|------------------|------|------|------|-----|
| f = 20 MHz)   | f <sub>T</sub>   | >50  | >50  | >50  | MHz |
| Collector-base capacitance  | , i              |      |      |      |     |
| $(V_{CBO} = 10 \text{ V}; f = 1 \text{ MHz})$                       | C <sub>CBO</sub> | <25  | <20  | <15  | рF  |
| Emitter-base capacitance  |                  |      |      | İ    |     |
| $(V_{EBO} = 0.5 \text{ V}; f = 1 \text{ MHz})$                      | C <sub>EBO</sub> | <80  | <80  | <80  | рF  |
| Noise figure  |                  |      |      |      |     |
| $(I_{\rm C} = 100 \mu{\rm A}; V_{\rm CE} = 10 {\rm V};$             |                  |      |      |      |     |
| $f = 1 \text{ kHz}$ ; $\Delta f = 200 \text{ Hz}$ ;                 |                  |      |      |      |     |
| $R_{\rm g} = 1 \text{ k}\Omega$ )                                   | NF               | 3.5  | 3.5  | 3.5  | dB  |
| Switching times   |                  |      |      |      |     |
| $I_{\rm C} = 100  {\rm mA};$  |                  |      |      |      |     |
| I <sub>B1</sub> approx. – I <sub>B2</sub> approx. 5 mA              | ton              | <200 | <200 | <200 | ns  |
|   | $t_{off}$        | <850 | <850 | <850 | ns  |

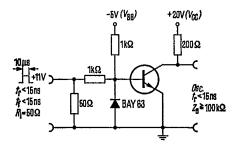
### 25C D ■ 8235605 0004809 7 ■ SIEG

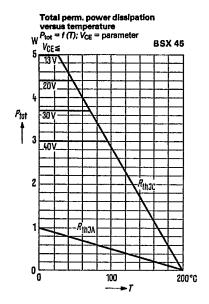
25C 04809 D T-35-/2

**BSX 45 BSX 46 BSX 47** 

### - SIEMENS AKTIENGESELLSCHAF -

Test circuit for switching times





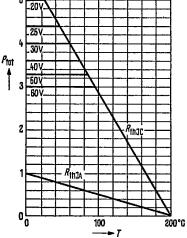
versus temperature

P<sub>tot</sub> = f(T); V<sub>CE</sub> = parameter

W

V<sub>CE</sub>≤ **BSX 46** 5 Zoy

Total perm. power dissipation



A-10 2171

versus temperature Ptot= f (T); V<sub>CE</sub> = parameter BSX 47 V<sub>CE</sub>≤ .20V 60V .80V RINJA 100 200°C

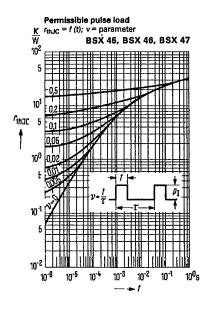
Total perm. power dissipation

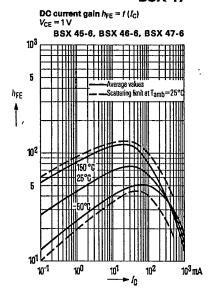
855

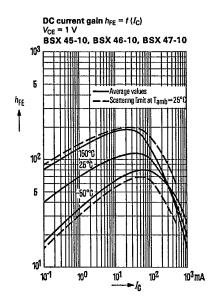
## 25C D 8235605 0004810 3 SIEG 25C 04810 D 7-35-77

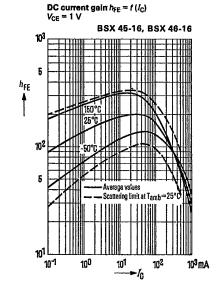
### SIEMENS AKTIENGESELLSCHAF

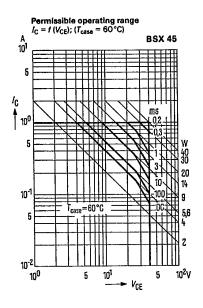
BSX 45 BSX 46 BSX 47

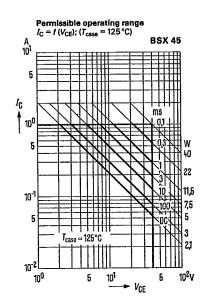


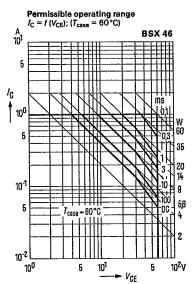


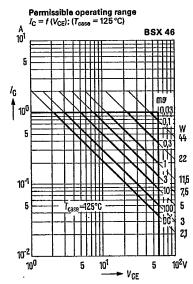






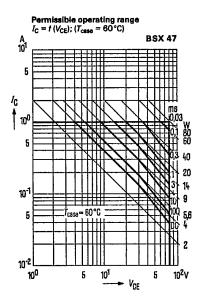


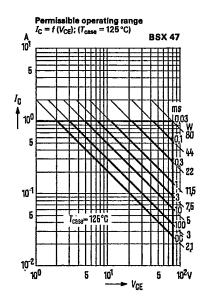


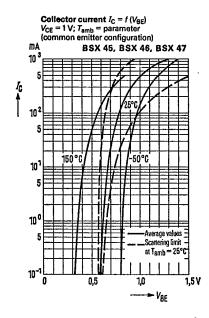


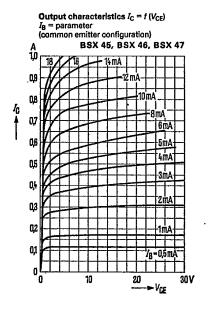
The permissible operating ranges apply to single pulses (v = C). For pulse sequences the power dissipation has to be reduced in accordance with the diagram "permissible pulse load".

857









a

- :

858 2174 A-13

25C 04813 DT-35-17

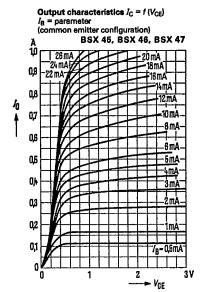
**BSX 45 BSX 46** 

### - SIEMENS AKTIENGESELLSCHAF

**BSX 47** 

Z VCE

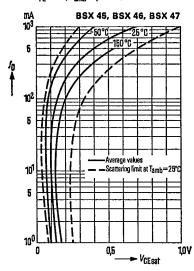
3 V



I<sub>B</sub> = parameter (common emitter configuration) BSX 45, BSX 46, BSX 47 mA 100 30

Output characteristics  $I_C = f(V_{CE})$ 

Saturation voltage  $V_{\text{CEsat}} = f(I_{\text{C}})$  $h_{\text{FE}} = 10$ ;  $T_{\text{amb}} = \text{parameter}$ 

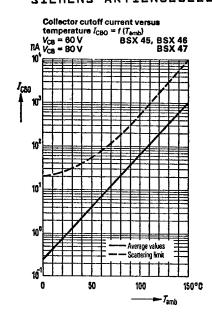


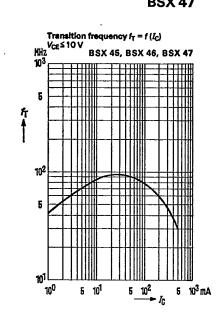
Saturation voltage  $V_{BEsat} = f(I_C)$ h<sub>FE</sub> = 10; V<sub>CE</sub> = 1V; T<sub>amb</sub> = parameter BSX 45, BSX 46, BSX 47 Average values 101 5 100 1,0 VBE sat 1,57

#### 25C D ■ 8235605 0004814 0 ■ SIEG 25C 04814 DT-35-17

BSX 45 BSX 46 BSX 47

### - SIEMENS AKTIENGESELLSCHAF





860 -

2176

B-01